

Features

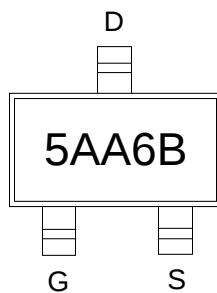
- Fast switching capability
- 100% avalanche tested
- Improved dv/dt capability

Product Summary

V_{DS}	$R_{DS(ON)}$ TYP	I_D
500V	16Ω@10V	0.6A

Application

- Switch Mode Power Supply (SMPS)
- Uninterruptible Power Supply (UPS)
- Power Factor Correction (PFC)

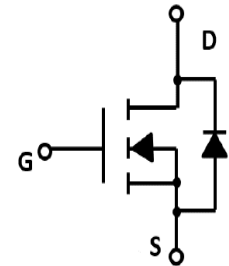


5AA6B: Device code

Marking and pin assignment



SOT-23-3L top view



Schematic diagram



Halogen-Free

Absolute Maximum Ratings (TA=25°C unless otherwise noted)

Symbol	Parameter	Rating	Unit
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Common Ratings (TC=25°C Unless Otherwise Noted)

V _{DS}	Drain-Source Breakdown Voltage		500	V
V _{GS}	Gate-Source Voltage		±30	V
T _J	Maximum Junction Temperature		150	°C
T _{STG}	Storage Temperature Range		-50 to 155	°C
I _S	Diode Continuous Forward Current	Tc=25°C	0.6	A

Mounted on Large Heat Sink

I_{DM}	Pulse Drain Current Tested	$T_C=25^{\circ}C$	2.4	A
I_D	Continuous Drain Current	$T_C=25^{\circ}C$	0.6	A
P_D	Maximum Power Dissipation	$T_C=25^{\circ}C$	0.5	W
$R_{\theta JA}$	Thermal Resistance Junction-Ambient		150	°C/W

Ordering Information (Example)

Type	Package	Marking	Minimum Package(pcs)	Inner Box Quantity(pcs)	Outer Carton Quantity(pcs)	Delivery Mode
MLSK5AA6B	SOT-23-3L	5AA6B	3,000	45,000	180,000	7"reel

Electrical Characteristics (TJ=25°C unless otherwise noted)						
Symbol	Parameter	Condition	Min	Typ	Max	Unit
Static Electrical Characteristics @ TJ = 25°C (unless otherwise stated)						
BV _{(BR)DSS}	Drain-Source Breakdown Voltage	V _{GS} =0V, I _D =250μA	500	--	--	V
I _{DSS}	Zero Gate Voltage Drain Current	V _{DS} =500V, V _{GS} =0V	--	--	1.0	μA
I _{GSS}	Gate-Body Leakage Current	V _{GS} =±30V, V _{DS} =0V	--	--	±100	nA
V _{GS(th)}	Gate Threshold Voltage	V _{DS} =V _{GS} , I _D =250μA	0.8	--	2.0	V
R _{DS(on)}	Drain-Source On-State Resistance	V _{GS} =10V, I _D =0.3A	--	16	25	Ω
Dynamic Electrical Characteristics @ TJ = 25°C (unless otherwise stated)						
C _{ISS}	Input Capacitance	V _{DS} =25V, V _{GS} =0V, f=1MHz	--	51	--	pF
C _{OSS}	Output Capacitance		--	10	--	pF
C _{RSS}	Reverse Transfer Capacitance		--	1.2	--	pF
Switching Characteristics						
Q _g	Total Gate Charge	V _{DD} =400V, I _D =0.6A, V _{GS} =10V	--	5	--	nC
Q _{gs}	Gate Source Charge		--	1.5	--	nC
Q _{gd}	Gate Drain Charge		--	1.4	--	nC
t _{d(on)}	Turn-on Delay Time	V _{DD} =250V, I _D =0.3A, V _{GS} =10V, R _G =25Ω	--	2.2	--	nS
t _r	Turn-on Rise Time		--	36	--	nS
t _{d(off)}	Turn-Off Delay Time		--	18	--	nS
t _f	Turn-Off Fall Time		--	65	--	nS
Source- Drain Diode Characteristics						
V _{SD}	Forward on voltage	Tj=25°C, Is=0.6A	--	--	1.2	V

Typical Operating Characteristics

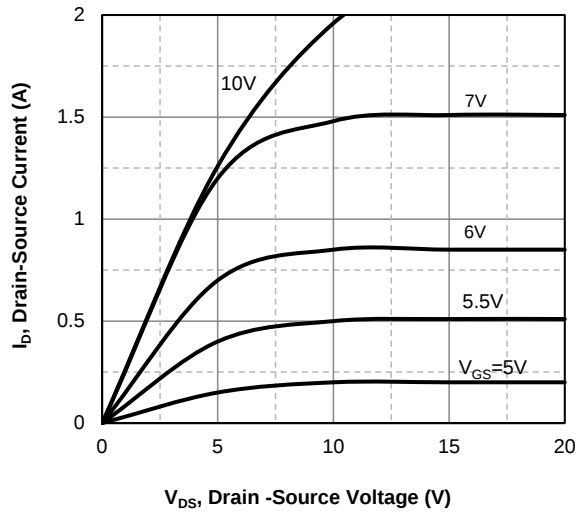


Fig1. Typical Output Characteristics

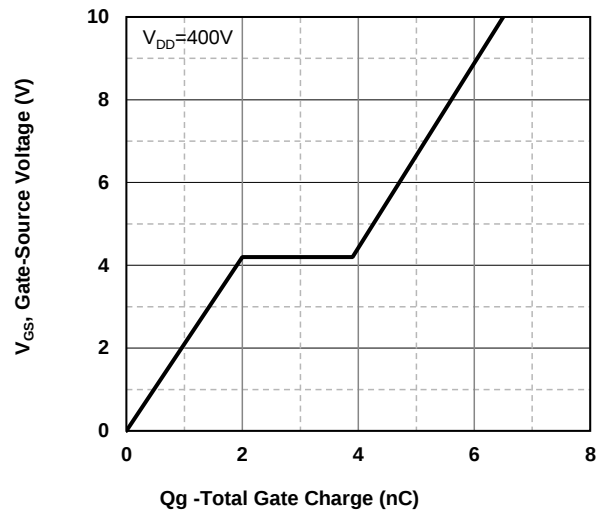


Fig2. Typical Gate Charge Vs. Gate-Source Voltage

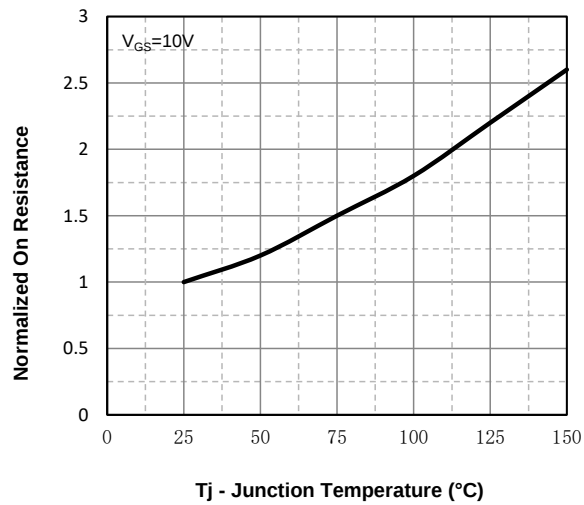


Fig3. Normalized On-Resistance Vs. Temperature

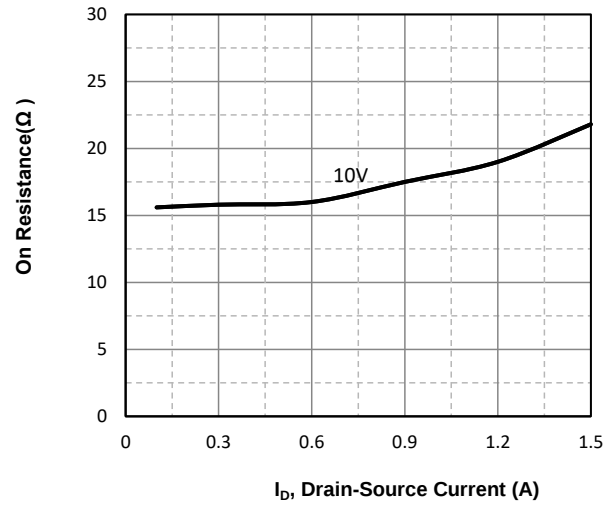


Fig4. On-Resistance Vs. Drain-Source Current

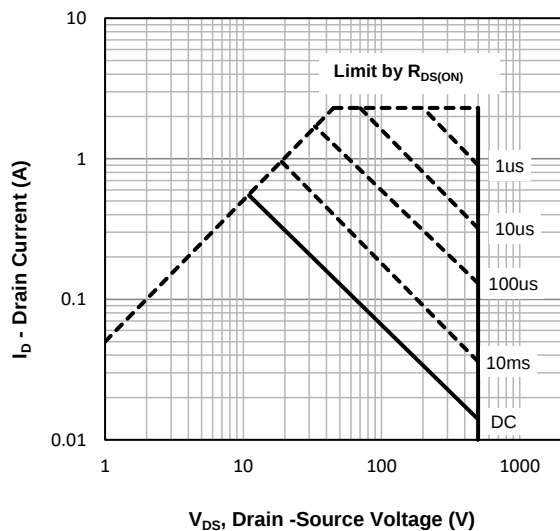


Fig5. Maximum Safe Operating Area

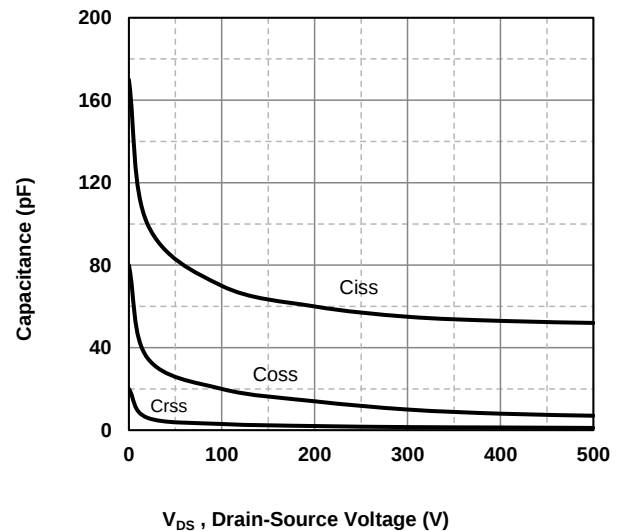
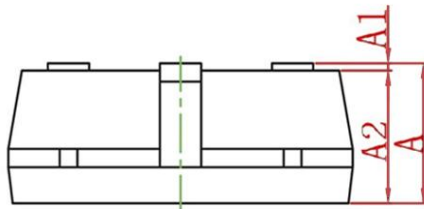
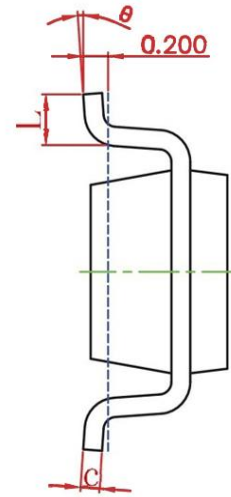
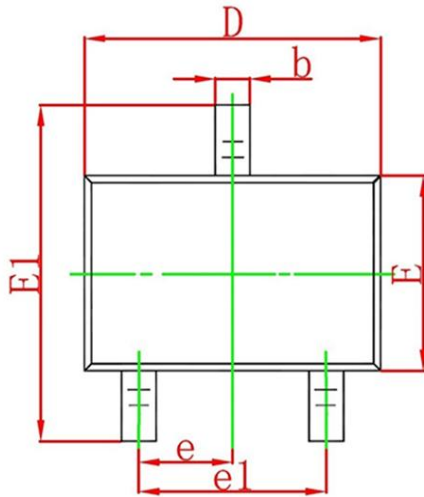


Fig6. Typical Capacitance Vs. Drain-Source Voltage

SOT-23-3L Package information



Symbol	Dimensions in Millimeters(mm)		Dimensions In Inches	
	Min	Max	Min	Max
A	1.050	1.250	0.042	0.050
A1	0.000	0.100	0.000	0.004
A2	1.050	1.150	0.042	0.046
b	0.300	0.500	0.012	0.020
c	0.100	0.200	0.004	0.008
D	2.820	3.020	0.112	0.120
E	1.500	1.700	0.060	0.068
E1	2.650	2.950	0.106	0.118
e	0.950TYP		0.037TYP	
e1	1.800	2.000	0.071	0.079
L	0.300	0.600	0.012	0.024
θ	0°	8°	0°	8°